

# **Surface Mount Ultrafast Power Rectifiers**

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

- \* Low Power Loss, High efficiency
- \* Glass Passivated chips junction
- \* 150 °C Operating Junction Temperature

- \* Low Stored Charge Majority Carrier Conduction

  \* Low Forward Voltage Drop , High Current Capability

  \* High-Switching Speed 50 & 75 Nanosecond Recovery Time
- \* Small Compact Surface Mountable Package with J-Bend Lead
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

## **MAXIMUM RATINGS**

Characteristic	Symbol	MU17	MU18	MU19	MU110	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	500	600	800	1000	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	350	420	560	700	V
Average Rectifier Forward Current	l <sub>o</sub>	1.0			Α	
Non-Repetitive Peak Surge Current ( Surge applied at rate load conditions halfware,single phase,60Hz )	FSM	25			Α	
Operating and Storage Junction Temperature Range	$T_{j}$ , $T_{stg}$	- 65 to + 150		°C		

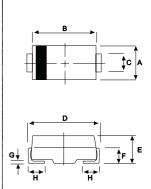
## **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	MU17	MU18	MU19	MU110	Unit
Maximum Instantaneous Forward Voltage $(I_F=1.0 \text{ Amp}, T_C=25 ^{\circ}\text{C})$	V <sub>F</sub>	1.	50	1.	75	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, T <sub>c</sub> = 25 °C) ( Rated DC Voltage, T <sub>c</sub> = 125 °C)	I <sub>R</sub>	5.0 50		uA		
Reverse Recovery Time (I <sub>F</sub> = 0.5 A, I <sub>R</sub> =1.0 , I <sub>rr</sub> =0.25 A)	T <sub>rr</sub>		50		75	ns
Typical Junction Capacitance (Reverse Voltage of 4 volt & f=1 MHz)	C <sub>P</sub>	1	5	1	0	pF

#### **ULTRA FAST RECTIFIERS**

1.0 AMPERES 500 -- 1000 VOLTS





DIM	MILLMETERS			
	MIN	MAX		
Α	3.30	3.90		
В	4.20	4.60		
С	1.80	2.20		
D	4.90	5.60		
Ε	1.90	2.50		
F		1.30		
G		0.22		
Н	0.85	1.45		
	*			

CASE---

Transfer molded plastic

POLARITY---Cathode indicated polarity band

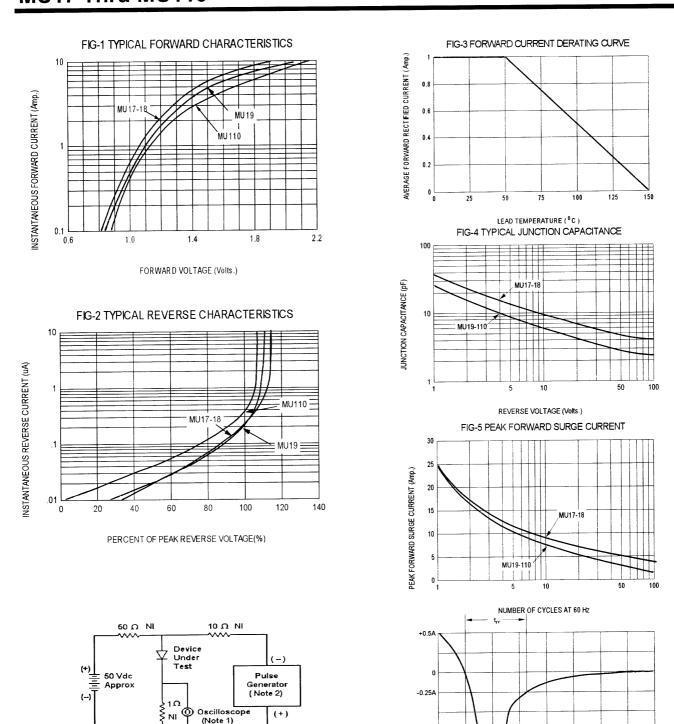


Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

Set time base for 20 ns/div

(Note 1)

Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M  $\Omega$  , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50  $\Omega$ 



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